Photocouplers Photorelay

TLP241B,TLP241BF

1. Applications

- Mechanical relay replacements
- Security Systems
- Heating, ventilation and air conditioning (HVAC)
- ATE (Automatic Test Equipment)
- Factory Automation (FA)
- Battery Management System (BMS) (Non-Automotive)

2. General

The TLP241B and TLP241BF photorelay consist of a photo MOSFET optically coupled to an infrared light emitting diode. They are housed in a 4-pin DIP package. They provide an isolation voltage of 5000 Vrms, making them suitable for applications that require reinforced insulation.

3. Features

(1) Halogen-free

For details, see "Devices in Halogen-Free Resin Packages" at the end of this datasheet.

- (2) Normally opened (1-Form-A)
- (3) OFF-state output terminal voltage: 100 V (min)
- (4) Trigger LED current: 3 mA (max)
- (5) ON-state current: 2.0 A (max)
- (6) ON-state resistance: $200 \text{ m}\Omega$
- (7) Isolation voltage: 5000 Vrms (min)
- (8) Safety standards

UL-recognized: UL 1577, File No.E67349

cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

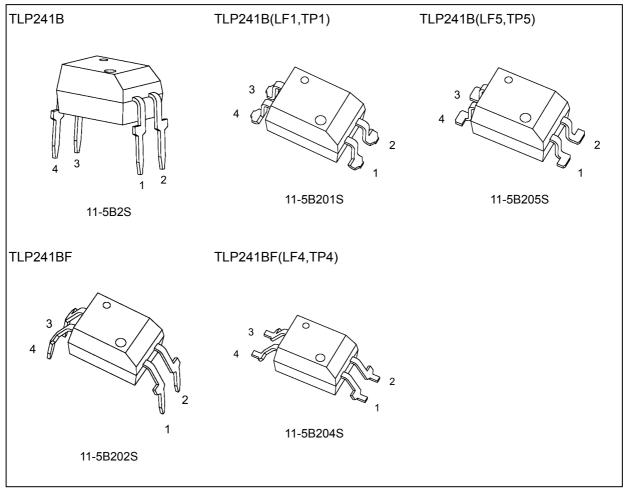
VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When an EN 60747-5-5 approved type is needed, please designate the Option (D4).

4. Mechanical Parameters

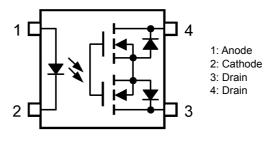
Characteristics	7.62-mm Pitch TLP241B	10.16-mm Pitch TLP241BF	Unit
Creepage distances	7.0 (min)	8.0 (min)	mm
Clearance distances	7.0 (min)	8.0 (min)	
Internal isolation thickness	0.4 (min)	0.4 (min)	

5. Packaging (Note)

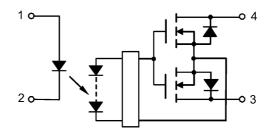


Note: Through-hole type: TLP241B, TLP241BF Lead forming option: (LF1), (LF4), (LF5) Taping option: (TP1), (TP4), (TP5)

6. Pin Assignment



7. Internal Circuit



8. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

	Characteristics	3	Symbol	Note	Rating	Unit
LED	Input forward current		l _F		30	mA
	Input forward current derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_F / \Delta T_a$		-0.3	mA/°C
	Input forward current (pulsed)	(100 μs pulse, 100 pps)	I _{FP}		1	Α
	Input reverse voltage		V _R		6	V
	Input power dissipation		PD		50	mW
	Input power dissipation derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta P_D / \Delta T_a$		-0.5	mW/°C
	Junction temperature		Tj		125	°C
Detector	OFF-state output terminal voltage		V _{OFF}		100	V
	ON-state current		I _{ON}		2.0	Α
	ON-state current derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_{ON} / \Delta T_a$		-20	mA/°C
	ON-state current (pulsed)	(t = 100 ms, Duty = 1/10)	I _{ONP}		6.0	Α
	Output power dissipation		Po		550	mW
	Output power dissipation derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta P_0 / \Delta T_a$		-5.5	mW/°C
	Junction temperature		Tj		125	°C
Common	Storage temperature		T _{stg}		-55 to 125	°C
	Operating temperature		T _{opr}		-40 to 110	°C
	Lead soldering temperature	(10 s)	T _{sol}		260	°C
	Isolation voltage	AC, 60 s, R.H. ≤ 60 %	BVS	(Note 1)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

9. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V _{DD}		_	_	80	V
Input forward current	١ _F		5	10	25	mA
ON-state current	I _{ON}		_	_	2.0	А
Operating temperature	T _{opr}		-20	_	85	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

10. Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V _F		I _F = 10 mA	1.50	1.65	1.80	V
	Input reverse current	I _R		V _R = 5 V	_		10	μA
	Input capacitance	Ct		V = 0 V, f = 1 MHz		50	_	pF
Detector	OFF-state current	I _{OFF}		V _{OFF} = 100 V		0.01	1	μA
	Output capacitance	C _{OFF}		V = 0 V, f = 1 MHz	_	300	_	pF

11. Coupled Electrical Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		I _{ON} = 1.0 A	_	0.4	3	mA
Return LED current	I _{FC}		I _{OFF} = 10 μA	0.01	_	—	
ON-state resistance	R _{ON}		I _{ON} = 2.0 A, I _F = 5 mA, t < 1 s	_	110	200	mΩ

Note 1: Thermally saturated state.

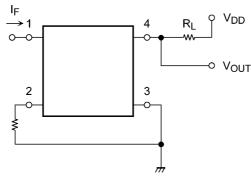
12. Isolation Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz		0.4	_	pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. \leq 60 %	$5 imes 10^{10}$	10 ¹⁴	—	Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	5000	_	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

13. Switching Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}		See Fig. 13.1.	_	0.8	3	ms
Turn-off time	t _{OFF}		R_{L} = 200 Ω, V_{DD} = 20 V, I_{F} = 5 mA		0.2	0.5	



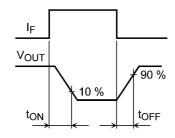
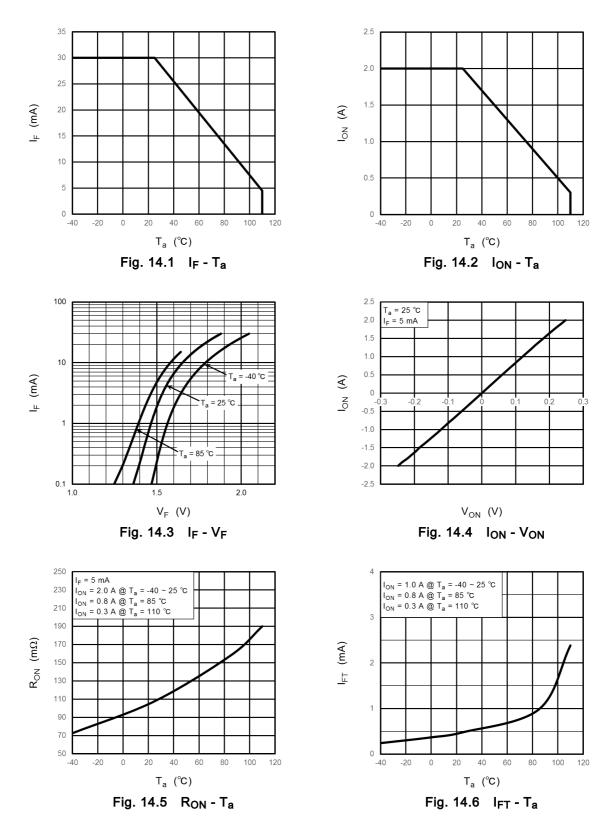
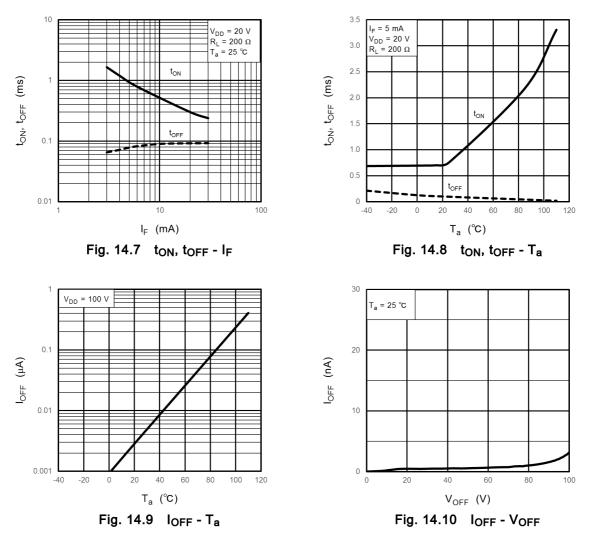


Fig. 13.1 Switching Time Test Circuit and Waveform

14. Characteristics Curves (Note)





Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

15. Soldering and Storage

15.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

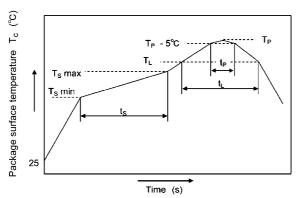
• When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Τs	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate $(T_L \text{ to } T_P)$			3	°C/s
Liquidus temperature	TL	217		°C
Time above T_L	tL	60	150	s
Peak temperature	Τ _Ρ		260	°C
Time during which T_c is between (T _P – 5) and T_P	t₽		30	s
Ramp-down rate $(T_P \text{ to } T_L)$			6	°C/s

An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

• When using soldering flow

Preheat the device at a temperature of 150 $^{\circ}$ C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 $^{\circ}$ C within 10 seconds is recommended.

Flow soldering must be performed once.

When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

15.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

16. Ordering Information (Example of Item Name)

Item Name	Packaging (Note 1)	VDE Option	Packing (MOQ)
TLP241BF	ТН		Magazine (100 pcs)
TLP241B(LF1,F	LF1		Magazine (100 pcs)
TLP241B(LF5,F	LF5		Magazine (100 pcs)
TLP241B(TP1,F	LF1		Tape and reel (1500 pcs)
TLP241B(TP5,F	LF5		Tape and reel (1500 pcs)
TLP241B(D4,F	TH	EN 60747-5-5	Magazine (100 pcs)
TLP241B(D4,LF1,F	LF1	EN 60747-5-5	Magazine (100 pcs)
TLP241B(D4,LF5,F	LF5	EN 60747-5-5	Magazine (100 pcs)
TLP241B(D4,TP1,F	LF1	EN 60747-5-5	Tape and reel (1500 pcs)
TLP241B(D4,TP5,F	LF5	EN 60747-5-5	Tape and reel (1500 pcs)
TLP241BF(F	TH, Wide forming		Magazine (100 pcs)
TLP241BF(LF4,F	LF4, Wide forming		Magazine (100 pcs)
TLP241BF(TP4,F	LF4, Wide forming		Tape and reel (1000 pcs)
TLP241BF(D4,F	TH, Wide forming	EN 60747-5-5	Magazine (100 pcs)
TLP241BF(D4LF4,F	LF4, Wide forming	EN 60747-5-5	Magazine (100 pcs)
TLP241BF(D4TP4,F	LF4, Wide forming	EN 60747-5-5	Tape and reel (1000 pcs)

Note 1: TH: Through-hole, LF: Lead forming for surface mount

17. Devices in Halogen-Free Resin Packages

 \cdot This product is Halogen-Free

Toshiba Electronic Devices & Storage Corporation ("Toshiba") defines a "Halogen-Free resin semiconductor product" as a semiconductor product in which:

- (1) the encapsulating resins do not contain any of the following elements: bromine (Br), chlorine (Cl) and antimony (Sb), respectively, in an amount exceeding 0.09 weight percent, and do not contain chlorine and bromine in an aggregate amount exceeding 0.15 weight percent of the encapsulating resins, and/or
- (2) the resin portion(s) in printed circuit boards do not contain any of the following elements: bromine, chlorine and antimony, respectively, in an amount exceeding 0.09 weight percent, and do not contain chlorine and bromine in an aggregate amount exceeding 0.15 weight percent of the each resin portion(s) in printed circuit boards.

For avoidance of doubt, "Halogen-Free resin semiconductor product" does not mean, and Toshiba does not make any warranty of any kind, that said semiconductor product is entirely free of antimony or of any of the following elements of the halogen family: bromine, chlorine, iodine (I), fluorine (F) and astatine (At).

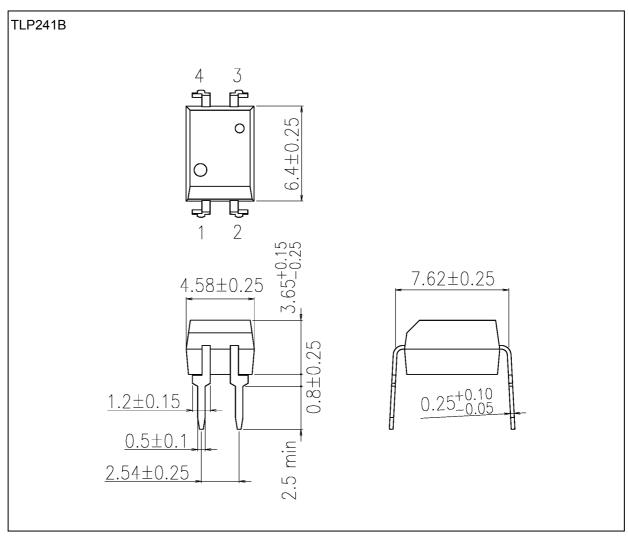
In addition, a Halogen-Free resin semiconductor product may contain antimony and/or any of the elements of the halogen family as mentioned in the above paragraph in one or more portion(s) of the semiconductor product other than the encapsulating resins and the resin portion(s) in printed circuit boards.

The information provided herein is accurate as of the date that it was provided, to the best of the knowledge and belief of the Toshiba Electronic Devices & Storage Corporation ("Toshiba"), Toshiba bases such knowledge and belief on information provided by third parties, and Toshiba makes no representation or warranty as to the accuracy of such third party information. Toshiba has taken and will continue to take, reasonable steps to provide accurate information to its customers, but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals.

Package Dimensions

TLP241B,TLP241BF

Unit: mm



Weight: 0.26 g (typ.)

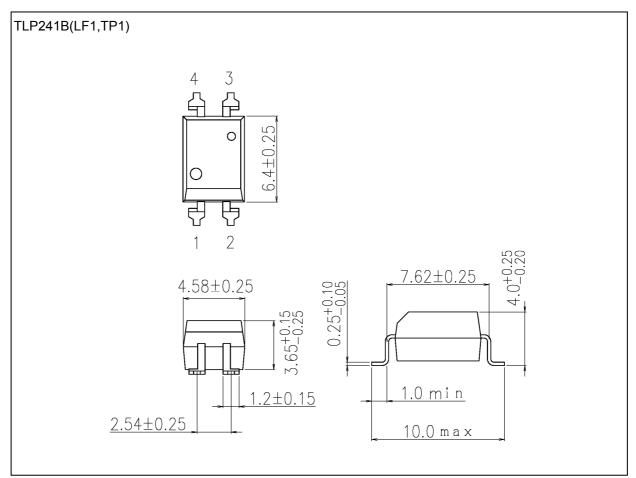
Package Name(s) TOSHIBA: 11-5B2S



Package Dimensions

TLP241B,TLP241BF

Unit: mm

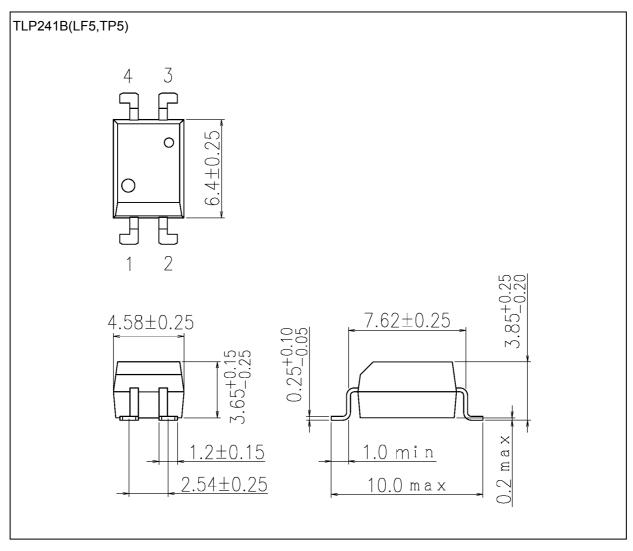


Weight: 0.25 g (typ.)

Package Name(s) TOSHIBA: 11-5B201S

Package Dimensions

Unit: mm



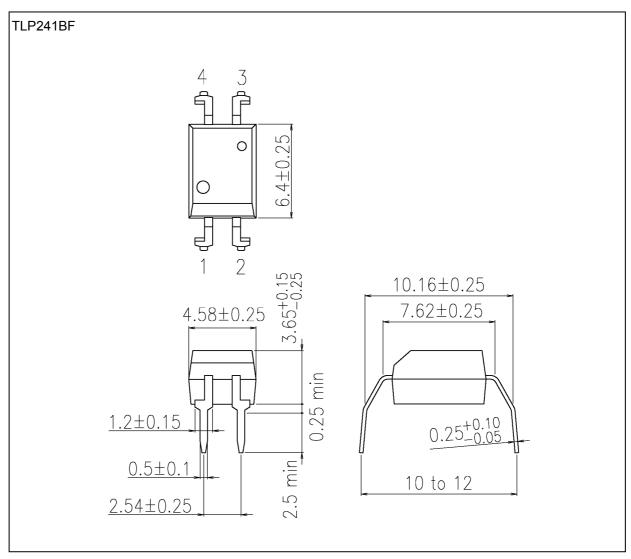
Weight: 0.25 g (typ.)

Package Name(s) TOSHIBA: 11-5B205S

Package Dimensions

TLP241B,TLP241BF

Unit: mm

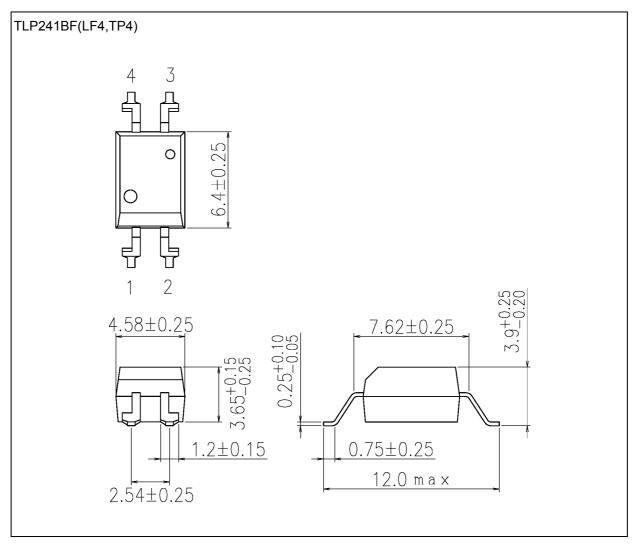


Weight: 0.26 g (typ.)

Package Name(s)
TOSHIBA: 11-5B202S

Package Dimensions

Unit: mm



Weight: 0.25 g (typ.)

Package Name(s) TOSHIBA: 11-5B204S

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